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ATTORNEY DOCKET NO.	CONFIRMATION NO.	
0756-2183	4214	

APPLICATION NO.	F	ILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/620,968		07/20/2000	Shunpei Yamazaki	0756-2183	4214	
22204	7590	10/28/2005		EXAMINER HA, NATHAN W		
NIXON PEA		•	•			
401 9TH STR SUITE 900	EEI, N	W		ART UNIT	PAPER NUMBER	
WASHINGT	ON, DC	20004-2128		2814		

DATE MAILED: 10/28/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application	on No.	Applicant(s)	V		
Office Action Summary		09/620,96		YAMAZAKI, SHU	JNPEI		
Office Action Sun	illialy	Examiner		Art Unit			
The MAILING DATE of th	is communication and	Nathan W		2814	al al vo		
Period for Reply	s communication app	pears on the	cover sneet with the	e correspondence a	aaress		
A SHORTENED STATUTORY I WHICHEVER IS LONGER, FRO Extensions of time may be available under after SIX (6) MONTHS from the mailing da If NO period for reply is specified above, th Failure to reply within the set or extended Any reply received by the Office later than earned patent term adjustment. See 37 Ci	DM THE MAILING D the provisions of 37 CFR 1.1 te of this communication. te maximum statutory period operiod for reply will, by statute three months after the mailin	OATE OF TH 136(a). In no eve will apply and wi e, cause the appl	IIS COMMUNICATION II expire SIX (6) MONTHS fro ication to become ABANDO	ON. timely filed om the mailing date of this NED (35 U.S.C. § 133).			
Status							
1) Responsive to communic	ation(s) filed on <u>17 A</u>	lugust 2005					
2a) This action is FINAL.	,	s action is n					
3) Since this application is in		•	•		ie merits is		
closed in accordance with	i the practice under <i>t</i>	Ex рапе Qu	ayle, 1935 C.D. 11,	453 O.G. 213.			
Disposition of Claims							
4)	is/are withdra wed. ted. ected to.	wn from coi					
Application Papers							
9) The specification is objected 10) The drawing(s) filed on Applicant may not request the Replacement drawing sheeted 11) The oath or declaration is	is/are: a) according and any objection to the s) including the correct	cepted or b) drawing(s) b tion is require	e held in abeyance. Sed if the drawing(s) is a	See 37 CFR 1.85(a). Objected to. See 37 C	•		
Priority under 35 U.S.C. § 119							
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 							
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawi 3) Information Disclosure Statement(s) (I Paper No(s)/Mail Date 10/02.	ng Review (PTO-948))	4) Interview Summa Paper No(s)/Mail 5) Notice of Informa 6) Other:	ry (PTO-413) Date I Patent Application (PT	⁻ O-152)		

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DETAILED ACTION

Claim Rejections - 35 USC § 112

1. The previous 112 rejection has been withdrawn.

Claim Rejections - 35 USC § 103

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims 2-3, 6, 9-10, 12-13,15-17, and 19-20 are rejected under 35 U.S.C. 103(a) as being unpatentable over Cunningham et al. (US 3,833,842, previously cited, hereinafter, Cunningham) and in view of Mori et al. (US 5,243,202, previously cited, hereinafter, Mori.)

In regard to claims 2, 9, 12, 16, and 19, in fig.12, Cunningham discloses a method of making a semiconductor device comprising steps of:

forming an insulating layer 119 comprising silicon nitride over a semiconductor substrate 70 by sputtering in an atmosphere consisting of nitrogen; see col. 12, lines 5-12. Cunningham does not expressly disclose that the amount of nitrogen is 75% volume or more.

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Mori, in fig. 7, discloses an analogous semiconductor device including the silicon nitride comprising nitrogen at 75% or more in order to have a film that has high break down voltage (col. 30, lines 5-25.)

Therefore, it would have been obvious to one of ordinary skilled in the art at the time of the invention was made to use a high volume of Nitrogen as taught by Mori in order to improve the break down voltage of the film.

In regard to claims 3, 6, 10, 13, 17, and 20, the above-mentioned references teach the layer is made by using RF sputtering. See [0074], for example.

In regard to claims 9 and 12, Cunningham further discloses the use of Aluminum electrodes; see col. 2, lines 34-38.

4. Claims 4, 7, 11, 14, 18 and 21 are rejected under 35 U.S.C. 103(a) as being unpatentable over Cunningham and Mori's as applied to claims 2-3, 5-6, 8, 15-17, 19-20, and 22 above, and further in view of Nomoto et al. (US 5,225,364, previously hereinafter Nomoto.)

In regard to claims 4, 7, 11, 14, 18 and 21 Cunningham discloses all of the claimed limitations as mentioned above except expressly teaches the device can be used in a matrix display. It is noted that the device of Cunningham in fact can be used in a matrix display device since it is a metallization device. It is used to carry out signal or power connection. However, in order to show the obviousness of this utility, Nomoto is incorporated herein. Nomoto discloses an analogous semiconductor device with substrate 1, silicon nitride insulating layer 5 and an aluminum electrode 8. The matrix has plurality devices that connect in rows and columns. Therefore, it is proper to

combine this structure to a metallization structure in order to carry out the intended product, or design choice of a product.

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention was made to adapt matrix device as taught by Nomoto in Cunningham's in order to carry out the advantage mentioned above.

Claims 5, 8, 15, and 22 are rejected under 35 U.S.C. 103(a) as being 5. unpatentable over Cunningham and Mori as applied to claims2-3, 6, 9-10, 12-13,15-17, and 19-20 above, and further in view of Yamazaki et al. (US 6,586,346, previously cited, herein, Yamazaki.)

In regard to claim 5, 8, 15, and 22, the above combination discloses all of the claimed limitations except the volumes of argon and halogen. Yamazaki discloses an analogous process and further includes the volumes of the argon and halogen as claimed in claims 5, 8, 15, and 22 in order to prevent fixed electric charges from being generated in the film (see the abstract.)

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention was made to use appropriate volumes of the argon and halogen materials in order to prevent fixed electric charges from being generated in the film.

Response to Arguments

6. . Applicant's arguments filed 8/17/05 have been fully considered but they are not persuasive. For instance, applicant submits that Mori does not teach the sputtering method. The applicant's arguments against the references individually, one cannot

show nonobviousness by attacking references individually where the rejections are based on combinations of references. See *In re Keller*, 642 F.2d 413, 208 USPQ 871 (CCPA 1981); *In re Merck & Co.*, 800 F.2d 1091, 231 USPQ 375 (Fed. Cir. 1986). In this case, Mori was used to incorporate with Cunningham to show the volume of nitrogen of at least 75%. This feature is stated in Mori's col. 30, lines 5-20, wherein the gas flow rates are shown, for example, nitrogen is 12.3.

Conclusion

7. THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Nathan W. Ha whose telephone number is (571) 272-1707. The examiner can normally be reached on M-TH 8:00-7:00(EST).

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael Fahmy can be reached on (571) 272-1705. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

Nathan Ha October 25, 2005

> HOAI PHAM PRIMARY EXAMINER